


## APPLICATION DATA SHEET

Electronic Version v14

Stylesheet Version v14.0

<b>Title of Invention</b>	SEMICONDUCTOR DEVICE FORMED BY IN-SITU MODIFICATION OF DIELECTRIC LAYER AND RELATED METHODS		
Application Type : regular, utility Attorney Docket Number : FIS920040083US1			
Correspondence address: Customer Number: 23550 			
<b>Inventor Information:</b>  <u>Inventor 1:</u> <b>Applicant Authority Type:</b> Inventor <b>Citizenship:</b> US <b>Given Name:</b> William <b>Middle Name:</b> G. <b>Family Name:</b> America <b>Residence:</b> <b>City of Residence:</b> Kingston <b>State of Residence:</b> NY <b>Country of Residence:</b> US <b>Address-1 of Mailing Address:</b> 243 City View Terrace <b>Address-2 of Mailing Address:</b> <b>City of Mailing Address:</b> Kingston <b>State of Mailing Address:</b> NY <b>Postal Code of Mailing Address:</b> 12401 <b>Country of Mailing Address:</b> US <b>Phone:</b> <b>Fax:</b> <b>E-mail:</b>			
<u>Assignee 1:</u> <b>Organization Name:</b> International Business Machines Corporation <b>Address-1 of Mailing Address:</b> New Orchard Road <b>Address-2 of Mailing Address:</b>			

**City of Mailing Address:** Armonk

**State of Mailing Address:** NY

**Postal Code of Mailing Address:** 10504

**Country of Mailing Address:** US

**Phone:**

**Fax:**

**E-mail:**